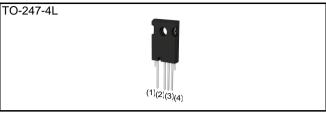


SCT4036KRHR Automotive Grade N-channel SiC power MOSFET

V _{DSS}	1200V
R _{DS(on)} (Typ.)	36mΩ
Ι _D ^{*1}	43A
P _D	176W

Outline



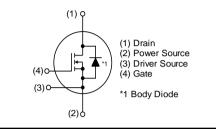
Features

- 1) Qualified to AEC-Q101
- 2) Low on-resistance
- 3) Fast switching speed
- 4) Fast reverse recovery
- 5) Easy to parallel
- 6) Simple to drive
- 7) Pb-free lead plating ; RoHS compliant

Application

- Automobile
- · Switch mode power supplies

Inner circuit



Please note Driver Source and Power Source are not exchangeable. Their exchange might lead to malfunction.

Packaging specifications

Packing	Tube
Reel size (mm)	-
Tape width (mm)	-
Basic ordering unit (pcs)	30
Taping code	C15
Marking	SCT4036KR
	Reel size (mm) Tape width (mm) Basic ordering unit (pcs) Taping code

•Absolute maximum ratings (T_{vj} = 25°C unless otherwise specified.)

Р	arameter		Symbol	Value	Unit
Drain - source voltage		V _{DSS}	1200	V	
Continuous drain	V - V	$T_c = 25^{\circ}C$	*1	43	Α
and source current	$V_{GS} = V_{GS_{on}}$	$T_c = 100^{\circ}C$	ا _D , I _S ^{*1}	30	А
Pulsed drain current	$V_{GS} = V_{GS_{on}}$	$T_c = 25^{\circ}C$	I _{D,pulse} *2	84	А
Body diode pulsed forwa	ard current	$T_c = 25^{\circ}C$	*1,*3 I _{S,pulse}	43	А
Body diode surge forward current		$V_{GS} = 0 V$	I _{S,pulse} *1,*4	84	Α
Gate - source voltage (DC)		V _{GSS_DC}	-4 to +21	V
Gate - source surge vol	tage (t _{surge} < 300)ns)	V_{GSS_surge} *5	-4 to +23	V
Recommended turn-on gate - source drive voltage		V _{GS_on} *6	+15 to +18	V	
Recommended turn-off gate - source drive voltage		V _{GS_off}	0	V	
Virtual junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-40 to +175	°C	

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

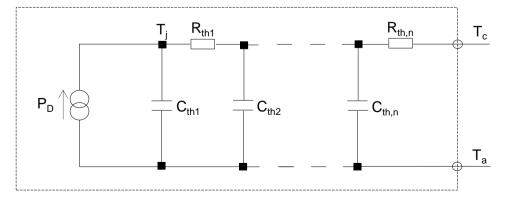
Deremeter	Symbol Conditions -			L locit		
Parameter			Min.	Тур.	Max.	Unit
Drain - Source breakdown	V	$V_{GS} = 0 V, I_{D} = 9.2 mA$				V
voltage	V _{(BR)DSS}	T _{vj} = 25°C	1200	-	-	v
		$V_{GS} = 0 V, V_{DS} = 1200V$				
Zero Gate voltage Drain current	I _{DSS}	T _{vj} = 25°C	-	1	80	μA
		T _{vj} = 150°C	-	10	-	
Gate - Source leakage current	I _{GSS+}	V_{GS} = +21V , V_{DS} = 0V	-	-	100	nA
Gate - Source leakage current		$V_{GS} = -4V$, $V_{DS} = 0V$	-	-	-100	nA
Gate threshold voltage	$V_{GS(th)}$ *7	$V_{DS} = 10V, I_{D} = 11.1mA$	2.8	-	4.8	V
		$V_{GS} = 18V, I_{D} = 21A$				
Static Drain - Source on - state resistance	R _{DS(on)} *8	T _{vj} = 25°C	-	36	47	mΩ
		T _{vj} = 150°C	-	72	-	
Gate input resistance	R_G	f = 1MHz, open drain	-	1	-	Ω

Thermal resistance

Parameter	Symbol	Values			Unit
Faranielei	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R_{thJC}^{*9}	-	0.65	0.85	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	4.9 ×10 ⁻²		C _{th1}	8.7 ×10 ⁻⁴	
R _{th2}	3.0 ×10 ⁻¹	K/W	C _{th2}	4.0 ×10 ⁻³	Ws/K
R _{th3}	3.0 ×10 ⁻¹		C _{th3}	5.2 ×10 ⁻²	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Demonster	O week of	Canditiana	Values			11-20	
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit	
Transconductance	g _{fs} *8	$V_{DS} = 10V, I_{D} = 21A$	-	11	-	S	
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	2335	-		
Output capacitance	C _{oss}	V _{DS} = 800V	-	70	-	pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	5	-		
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 800V	-	84	-	pF	
Total Gate charge	Q _g *8	$V_{DS} = 800V$	-	91	-		
Gate - Source charge	Q _{gs} *8	I _D = 21A V _{GS} = 18V	-	20	-	nC	
Gate - Drain charge	Q _{gd} *8 See Fig. 1-1, 1-2.		-	24	-		
Turn - on delay time	t _{d(on)} *8	$V_{DS} = 800V$ $I_{D} = 21A$	-	8.1	-		
Rise time	t _r *8	V _{GS} = +18V / 0V	-	15	-	20	
Turn - off delay time	t _{d(off)} *8	$R_G = 3.3\Omega$, L = 250µH E _{on} includes diode	-	29	-	ns	
Fall time	t _f *8	reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF	-	9.6	-		
Turn - on switching loss	E _{on} *8	See Fig. 2-1, 2-2, 2-3.	-	239	-		
Turn - off switching loss	E _{off} *8		-	26	-	μJ	
Short-circuit $V_{GS(on)} = +15V$	t _{sc} *9	V _{DS} ≤ 800V V _{DS,peak} ≤ 1200V	-	4.5	-	μs	
withstand time $V_{GS(on)} = +18V$		$T_{vj(start)} = 25^{\circ}C$ $R_{G} = 2.2\Omega$	-	4.0	-	μs	



•Body diode electrical characteristics (Source-Drain) (T_{vi} = 25°C unless otherwise specified)

Doromotor	Symbol	Symbol Conditions		Values		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward voltage	V_{SD}^{*8}	$V_{GS} = 0V, I_S = 21A$	-	3.3	-	V
Reverse recovery time	t _{rr} *8	$I_F = 21A$ $V_R = 800V$	-	9.2	-	ns
Reverse recovery charge	Q _{rr} *8	di/dt = 3700A/µs	-	140	-	nC
Peak reverse recovery current	I _{rrm} *8	$L_{\sigma} = 50$ nH, $C_{\sigma} = 10$ pF See Fig. 3-1, 3-2.	-	31	-	А

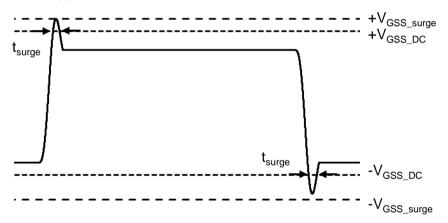
*1 Limited by maximum T_{vj} and for Max. R_{thJC} .

*2 Pulse width and duty cycle are limited by $T_{vj,max}$.

*3 Only for body-diode, Repititive pulse, PW \leq 1.5µs, Duty cycle \leq 5%

*4 When used as a protective function, PW \leq 10µs

*5 Example of acceptable V_{GS} waveform



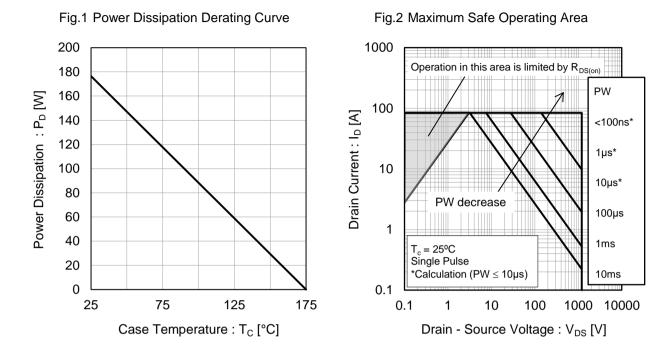
Please note especially when using driver source that V_{GSS_surge} must be in the range of absolute maximum rating.

- *6 Please be advised not to use SiC-MOSFETs with V_{GS} below 10V as doing so may cause thermal runaway.
- *7 Tested after applying $V_{GS} = 21V$ for 100ms.
- *8 Pulsed
- *9 The value is based on TO-247 package. Single Pulsed.
- *10 Measured conformable to JESD51-14.

See the application note "rthjc_measurement_and_usage_an-e.pdf". Link

URL: https://fscdn.rohm.com/en/products/databook/applinote/discrete/common/rthjc_measurement_and_usage_an-e.pdf



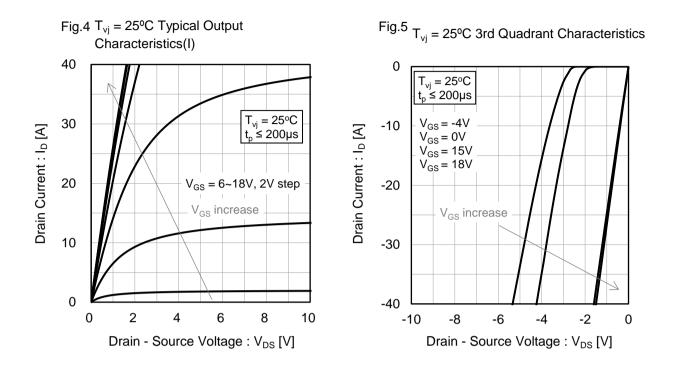


Impedance vs. Pulse Width 1 Transient Thermal Impedance : 0.1 Duty = 1 Z_{thJC} [K/W] 0.5 0.01 0.2 Duty increase 0.1 0.05 0.001 0.02 0.01 Single pulse $T_c = 25^{\circ}C$ 0.0001 1E-6 1E-5 1E-4 1E-3 1E-2 1E-1 1E+0 1E+1

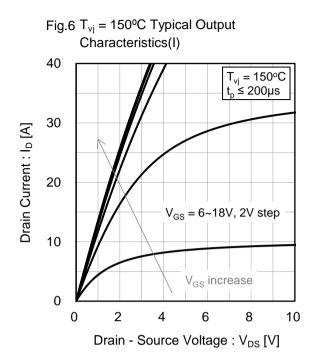
Pulse Width : PW [s]

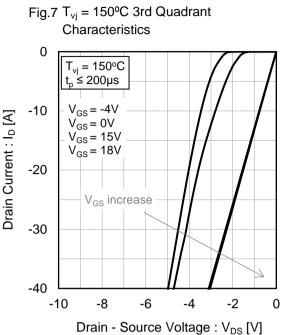
Fig.3 Typical Transient Thermal

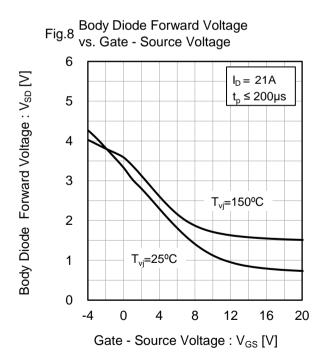














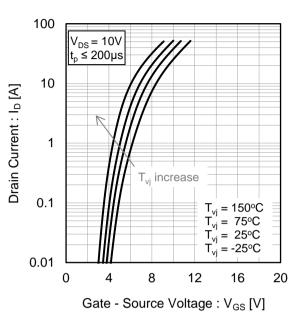
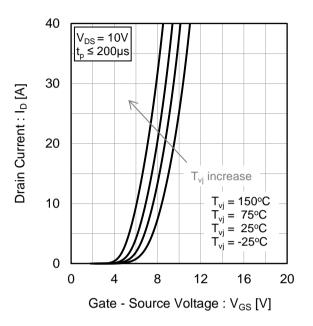


Fig.9 Typical Transfer Characteristics (I)

Fig.10 Typical Transfer Characteristics (II)



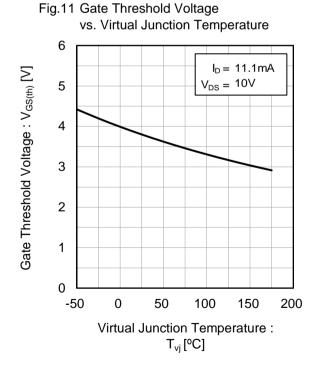
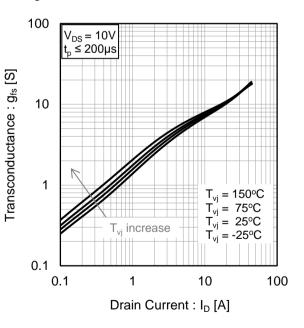
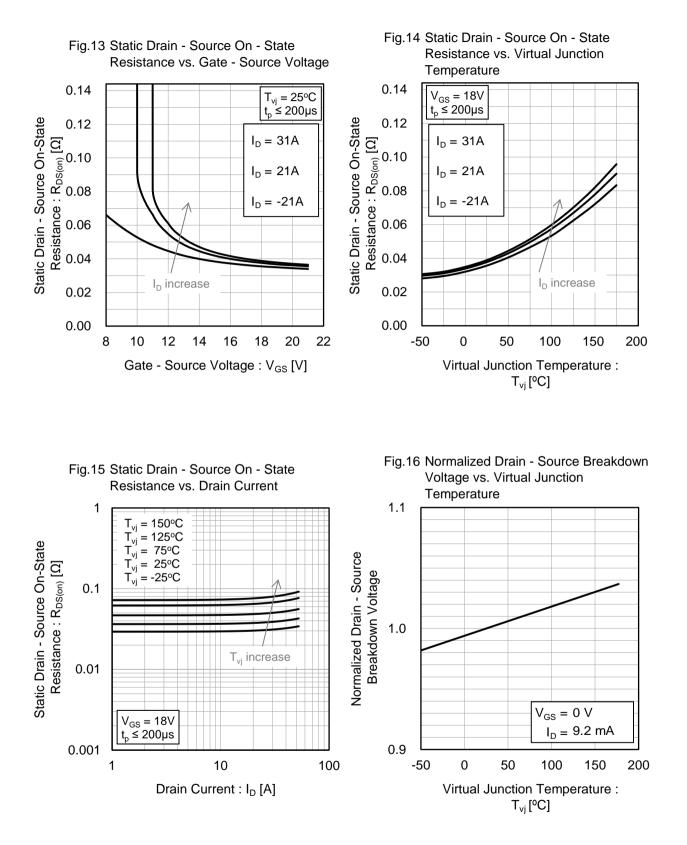


Fig.12 Transconductance vs. Drain Current



8/15





ROHM

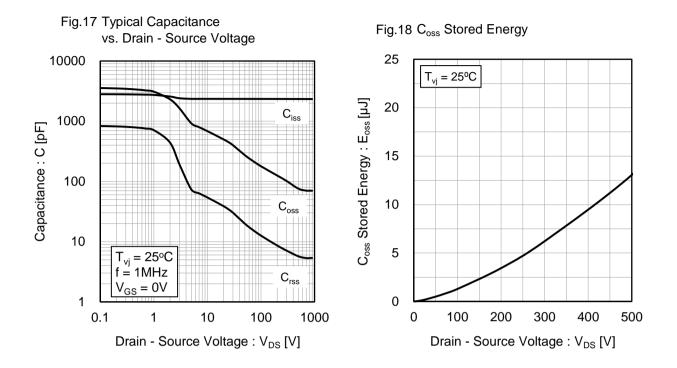
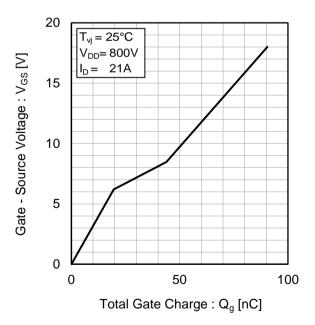
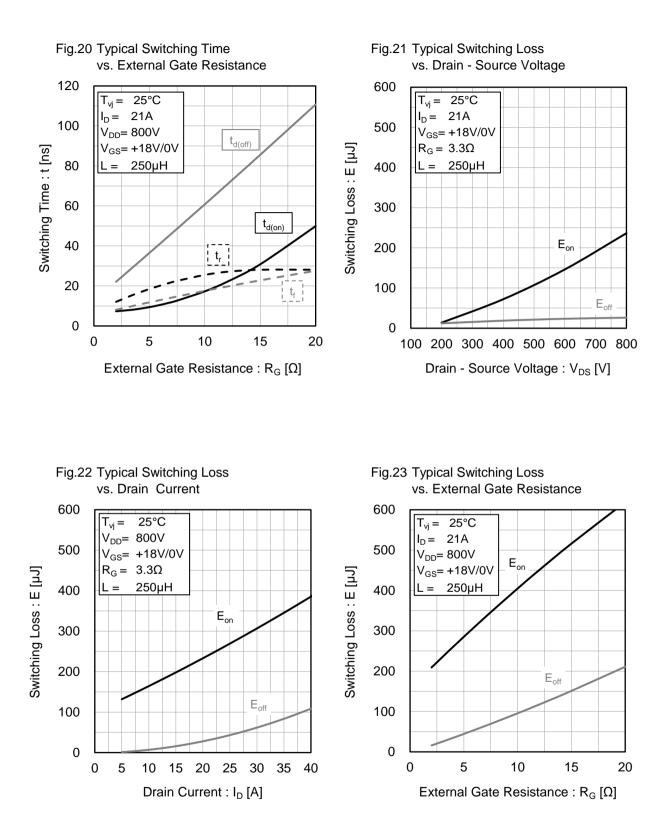


Fig.19 Dynamic Input Characteristics

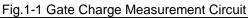






ROHM

Measurement circuits and waveforms



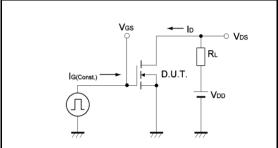


Fig.2-1 Switching Characteristics Measurement Circuit

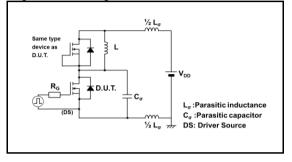


Fig.2-3 Waveforms for Switching Energy Loss

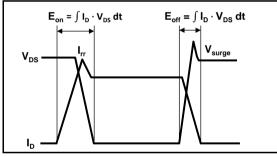


Fig.3-1 Reverse Recovery Time Measurement Circuit

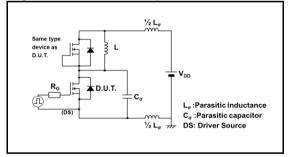


Fig.1-2 Gate Charge Waveform

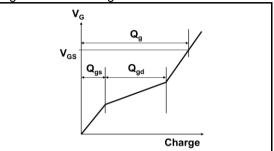


Fig.2-2 Waveforms for Switching Time

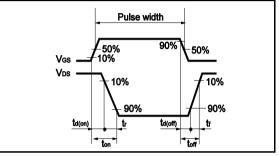
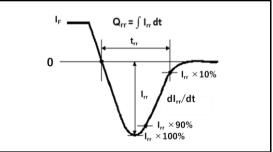
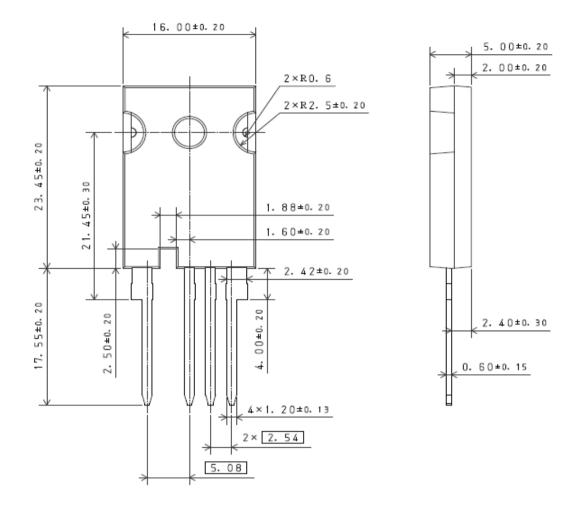


Fig.3-2 Reverse Recovery Waveform



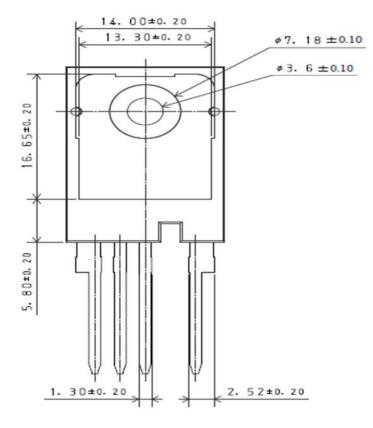


Package Dimensions



Unit: mm



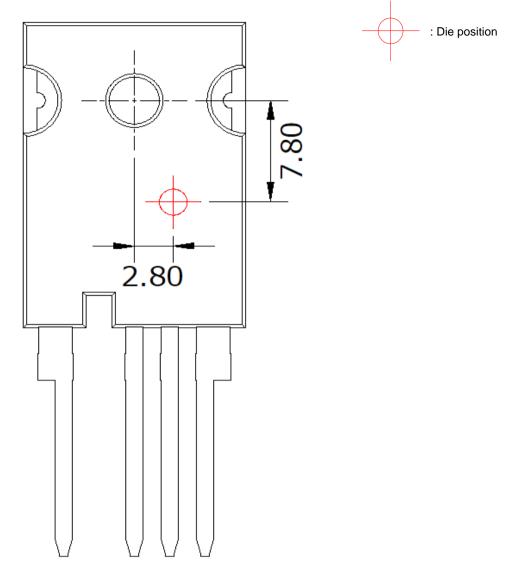


Unit: mm





Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm



	Notes
1)	The information contained herein is subject to change without notice.
2)	Before you use our Products, please contact our sales representative and verify the latest specifica- tions.
3)	Although ROHM is continuously working to improve product reliability and quality, semicon ductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.
4)	Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The periphera conditions must be taken into account when designing circuits for mass production.
5)	The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly any license to use or exercise intellectual property or other rights held by ROHM or any othe parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use or such technical information.
6)	The Products specified in this document are not designed to be radiation tolerant.
7)	For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, and power transmission systems.
8)	Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
9)	ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
10)	ROHM has used reasonable care to ensure the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
11)	Please use the Products in accordance with any applicable environmental laws and regulations such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
12)	When providing our Products and technologies contained in this document to other countries you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
13)	This document, in part or in whole, may not be reprinted or reproduced without prior consent of



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

General Precaution

- 1. Before you use our Products, you are requested to carefully read this document and fully understand its contents. ROHM shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any ROHM's Products against warning, caution or note contained in this document.
- 2. All information contained in this document is current as of the issuing date and subject to change without any prior notice. Before purchasing or using ROHM's Products, please confirm the latest information with a ROHM sales representative.
- 3. The information contained in this document is provided on an "as is" basis and ROHM does not warrant that all information contained in this document is accurate and/or error-free. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties resulting from inaccuracy or errors of or concerning such information.